

QS6U24

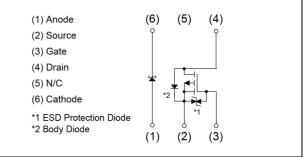
| V _{DSS} | -30V |
|----------------------------|-------|
| R _{DS(on)} (Max.) | 400mΩ |
| Ι _D | ±1.0A |
| P _D | 1.25W |

Features

- 1) The QS6U24 combines Pch MOSFET with a Schottky barrier diode in a single TSMT6 package.
- 2) High-speed switching, Low On-resistance.
- 3) Low voltage drive (4V drive).
- 4) Built-in Low V_F schottky barrier diode.
- 5) Pb-free lead plating ; RoHS compliant.

• Outline SOT-457T SC-95 TSMT6

Inner circuit



Packaging specifications

| | Packing | Embossed Tape |
|------|-----------------|------------------|
| | Reel size (mm) | 180 |
| Туре | Tape width (mm) | 8 |
| | Quantity (pcs) | 3000 |
| | Taping code | TR |
| | Marking | U24 |

Application

switching

• Absolute maximum ratings (T_a = 25°C ,unless otherwise specified)

<MOSFET>

| Parameter | Symbol | Value | Unit |
|--|--------------------|-------|-----------|
| Drain - Source voltage | V _{DSS} | -30 | V |
| Gate - Source voltage | V _{GSS} | ±20 | V |
| Continuous drain current | ۱ _D | ±1.0 | А |
| Pulsed drain current | I _{DP} *1 | ±2.0 | А |
| Continuous source current (body diode) | ۱ _S | -0.3 | А |
| Pulsed source current (body diode) | I _{SP} *1 | -1.2 | А |
| Power dissipation | P _D *3 | 0.9 | W/element |
| Junction temperature | Tj | 150 | °C |

• Absolute maximum ratings ($T_a = 25^{\circ}C$)

<Di>

| Parameter | Symbol | Value | Unit |
|---------------------------------|---------------------|-------|-----------|
| Repetitive peak reverse voltage | V _{RM} | 25 | V |
| Reverse voltage | V _R | 20 | V |
| Forward current | I _F | 0.7 | A |
| Forward current surge peak | I _{FSM} *2 | 3.0 | A |
| Power dissipation | P _D *3 | 0.7 | W/element |
| Junction temperature | Tj | 150 | °C |

<MOSFET + Di>

| Parameter | Symbol | Value | Unit |
|--|-------------------|-------------|---------|
| Power dissipation | P _D *3 | 1.25 | W/total |
| Operating junction and storage temperature range | T _{stg} | -55 to +150 | °C |

• Electrical characteristics ($T_a = 25^{\circ}C$)

<MOSFET>

| Devenenter | Queen al | Symbol Conditions | | Values | | |
|--|------------------------|---|------|--------|------|------|
| Parameter | Symbol | | | Тур. | Max. | Unit |
| Gate - Source leakage current | I _{GSS} | V_{GS} = ±20V, V_{DS} = 0V | - | - | ±10 | μA |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = -1mA | -30 | - | - | V |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = -30V, V _{GS} = 0V | - | - | -1 | μA |
| Gate threshold voltage | V _{GS(th)} | V _{DS} = -10V, I _D = -1mA | -1.0 | - | -2.5 | V |
| | | V _{GS} = -10V, I _D = -1A | - | 300 | 400 | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | V _{GS} = -4.5V, I _D = -0.5A | - | 500 | 700 | mΩ |
| | | V _{GS} = -4V, I _D = -0.5A | - | 600 | 800 | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = -10V, I _D = -0.5A | 0.5 | - | - | S |



•Electrical characteristics (T_a = 25°C)

<MOSFET>

| Parameter | Symbol | Conditions | | Values | | Unit |
|------------------------------|-------------------|--------------------------------------|------|--------|------|------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 90 | - | |
| Output capacitance | C _{oss} | V _{DS} = -10V | - | 25 | - | pF |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 16 | - | |
| Turn - on delay time | $t_{d(on)}^{*4}$ | $V_{DD} \simeq -15V, V_{GS} = -4.5V$ | - | 9 | - | |
| Rise time | t _r *4 | I _D = -0.5A | - | 7 | - | 20 |
| Turn - off delay time | $t_{d(off)}^{*4}$ | R _L = 30Ω | - | 18 | - | ns |
| Fall time | t_{f}^{*4} | R _G = 10Ω | - | 7 | - | |

• Gate charge characteristics ($T_a = 25^{\circ}C$)

<MOSFET>

| Deremeter | Symbol | Conditions | | Values | | Unit |
|----------------------|---------------------|---|------|--------|------|------|
| Parameter | Symbol Conditions – | | Min. | Тур. | Max. | Unit |
| Total gate charge | Q_g^{*4} | | - | 1.7 | - | |
| Gate - Source charge | Q _{gs} *4 | V _{DD} ≃ -15V, I _D = -1.0A V _{GS} = -5V | - | 0.6 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | | - | 0.4 | - | |

•Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

<MOSFET>

| Deremeter | Symbol | Conditions | | | Values | |
|-----------------|---|--|------|------|--------|------|
| Parameter | Symbol | | Min. | Тур. | Max. | Unit |
| Forward voltage | age V_{SD}^{*4} $V_{GS} = 0V, I_S = -0$ | V _{GS} = 0V, I _S = -0.3A | - | - | -1.2 | V |



• Electrical characteristics ($T_a = 25^{\circ}C$)

<Di>

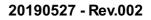
| Deremeter | Symbol | Conditions | Values | | | Linit |
|-----------------|----------------|-----------------------|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Forward voltage | V _F | I _F = 0.7A | - | - | 0.49 | V |
| Reverse current | I _R | V _R = 20V | - | - | 200 | μA |

*1 Pw \leq 10µs, Duty cycle \leq 1%

*2 60Hz•1 cycle

*3 Mounted on a ceramic board

*4 Pulsed





• Electrical characteristic curves < MOSFET>

Fig.1 Typical Capacitance vs. Drain -

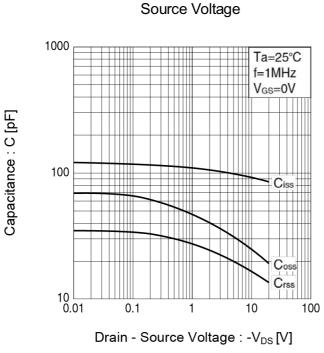
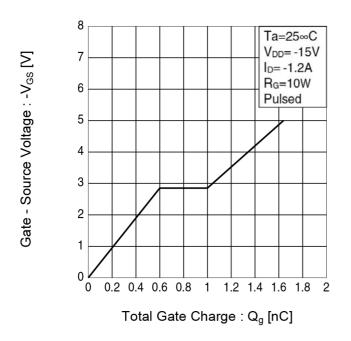


Fig.3 Dynamic Input Characteristics



Switching Time : t [ns]



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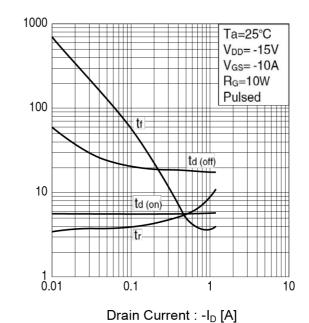


Fig.2 Switching Characteristics

Fig.5 Static Drain - Source On - State

Electrical characteristic curves <MOSFET>

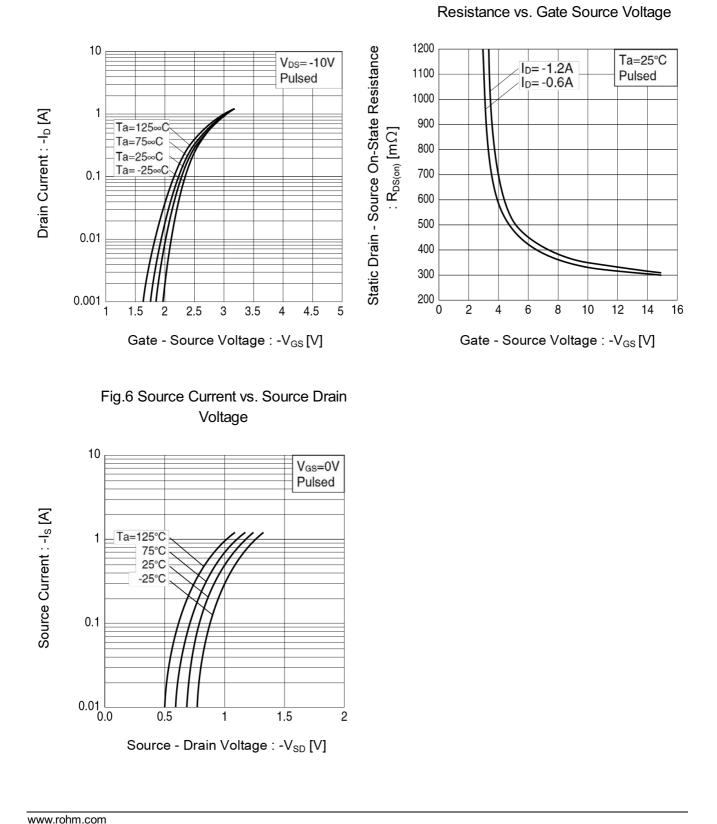
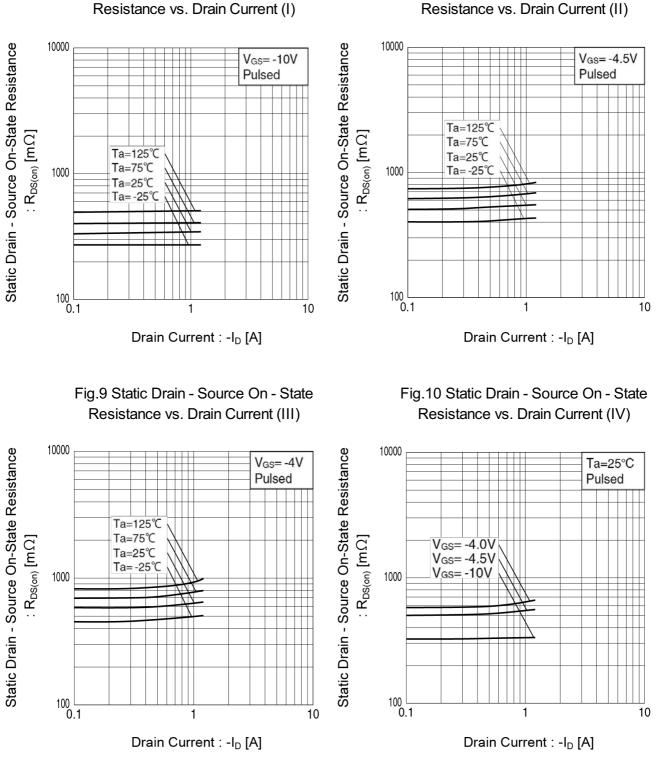


Fig.4 Typical Transfer Characteristics

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Electrical characteristic curves <MOSFET>

Fig.7 Static Drain - Source On - State



7/10



Fig.12 Reverse Current vs. Reverse

•Electrical characteristic curves < Diode >

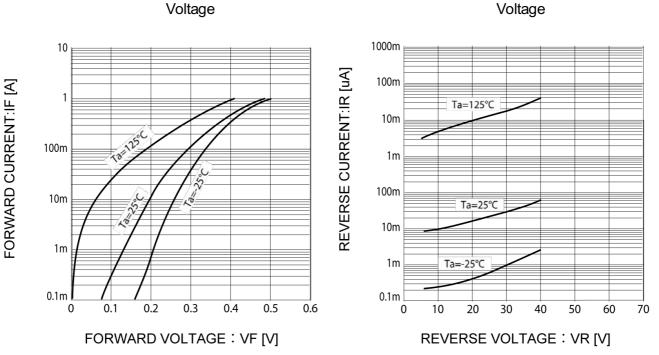


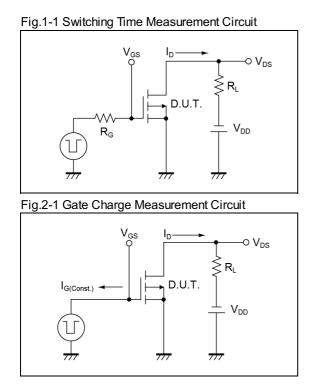
Fig.11 Forward Current vs. Forward Voltage

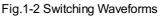
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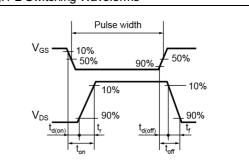
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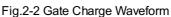


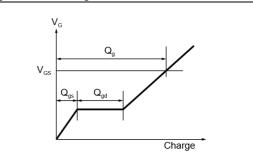
Measurement circuits









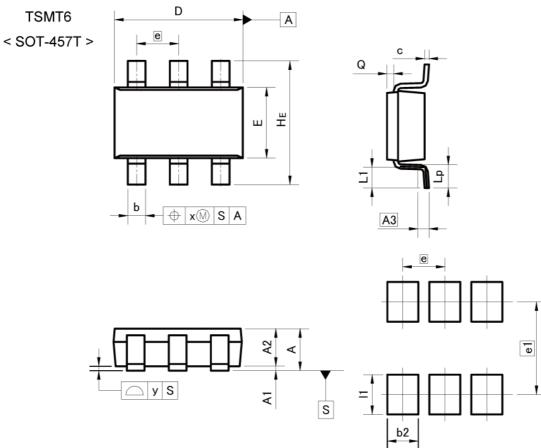


Notice

- SBD has a large reverse leak current compared to other type of diode. Therefore, it would raise a junction temperature, and increase a reverse power loss. Further rise of inside temperature would cause a thermal runaway. This built-in SBD has low V_F characteristics and therefore, higher leak current. Please consider enough the surrounding temperature, generating heat of MOSFET and the reverse current.
- 2. This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

| DIM - | MILIM | ETERS | INC | HES |
|-------|-------|-------|-------|-------|
| | MIN | MAX | MIN | MAX |
| A | 844 | 1.00 | | 0.039 |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 |
| A2 | 0.75 | 0.95 | 0.030 | 0.037 |
| A3 | 0. | 25 | 0.0 | 10 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| С | 0.10 | 0.26 | 0.004 | 0.010 |
| D | 2.80 | 3.00 | 0.110 | 0.118 |
| E | 1.50 | 1.80 | 0.059 | 0.071 |
| e | 0.95 | | 0.037 | |
| HE | 2.60 | 3.00 | 0.102 | 0.118 |
| L1 | 0.30 | 0.60 | 0.012 | 0.024 |
| Lp | 0.40 | 0.70 | 0.016 | 0.028 |
| Q | 0.05 | 0.25 | 0.002 | 0.010 |
| x | | 0.20 | - | 0.008 |
| У | 1 | 0.10 | E. | 0.004 |
| | MILIM | ETERS | INC | HES |
| DIM - | MIN | MAX | MIN | MAX |
| b2 |] | 0.70 | - | 0.028 |
| e1 | 2. | 10 | 0.0 | 83 |
| 11 | | 0.90 | | 0.035 |

Dimension in mm/inches



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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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